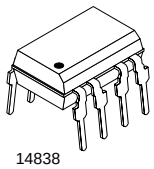
Dual Channel Optocoupler with Phototransistor Output

Description

The MCT6H and MCT62H consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 6-lead plastic dual inline package.
The elements are mounted on one leadframe using a **coplanar technique**, providing a fixed distance between input and output for highest safety requirements.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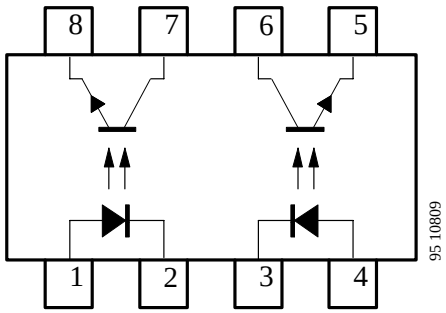
Applications

Galvanically separated circuits, non-interacting switches

Features

- **C**urrent **T**ransfer **R**atio (CTR) of typical 100%
- Isolation test voltage V_{IO} = 5 kV
- Low temperature coefficient of CTR
- Low coupling capacitance of typical 0.3 pF
- Wide ambient temperature range
- **U**nderwriters **L**aboratory (UL) 1577 recognized, file number E-76222
- **CSA** (C–UL) 1577 recognized, file number E-76222 – Double Protection
- Coupling System U



Order Instruction

Ordering Code	CTR Ranking	Remarks
MCT6H	> 50%	
MCT62H	> 100%	

Absolute Maximum Ratings

Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \le 10$ µs	I_{FSM}	1.5	A
Power dissipation	$T_{amb} \le 25$˚C	P_V	100	mW
Junction temperature		T_j	125	˚C

Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5$, $t_p \le 10$ ms	I_{CM}	100	mA
Power dissipation	$T_{amb} \le 25$˚C	P_V	150	mW
Junction temperature		T_j	125	˚C

Coupler

Parameter	Test Conditions	Symbol	Value	Unit
AC isolation test voltage (RMS)	t = 1 min	V_{IO} [1)]	5	kV
Total power dissipation	$T_{amb} \le 25$˚C	P_{tot}	250	mW
Ambient temperature range		T_{amb}	–40 to +100	˚C
Storage temperature range		T_{stg}	–55 to +125	˚C
Soldering temperature	2 mm from case, t ≤ 10 s	T_{sd}	260	˚C

1) Related to standard climate 23/50 DIN 50014

Electrical Characteristics (T_{amb} = 25°C)

Input (Emitter)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	I_F = 50 mA	V_F		1.25	1.6	V

Output (Detector)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector emitter voltage	I_C = 1 mA	V_{CEO}	70			V
Emitter collector voltage	I_E = 100 µA	V_{ECO}	7			V
Collector dark current	V_{CE} = 20 V, I_F = 0, E = 0	I_{CEO}			100	nA

Coupler

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
DC isolation test voltage	t = 2 s	V_{IO} [1)]	5			kV
Isolation resistance	V_{IO} = 1000 V, 40% relative humidity	R_{IO} [1)]		10^{12}		Ω
Collector emitter saturation voltage	I_F = 10 mA, I_C = 1 mA	V_{CEsat}			0.3	V
Cut-off frequency	I_F = 10 mA, V_{CE} = 5 V, R_L = 100 Ω	f_C		100		kHz
Coupling capacitance	f = 1 MHz	C_k		0.3		pF

1) Related to standard climate 23/50 DIN 50014

Current Transfer Ratio (CTR)

Parameter	Test Conditions	Type	Symbol	Min.	Typ.	Max.	Unit
I_C/I_F	V_{CE} = 5 V, I_F = 5 mA	MCT6H	CTR	0.5	1		
	V_{CE} = 5 V, I_F = 10 mA	MCT6H	CTR	0.6	1.2		
	V_{CE} = 5 V, I_F = 5 mA	MCT62H	CTR	1	2		

Switching Characteristics

Parameter	Test Conditions	Symbol	Typ.	Unit
Delay time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω (see figure 1)	t_d	3.0	µs
Rise time		t_r	3.0	µs
Fall time		t_f	4.7	µs
Storage time		t_s	0.3	µs
Turn-on time		t_{on}	6.0	µs
Turn-off time		t_{off}	5.0	µs

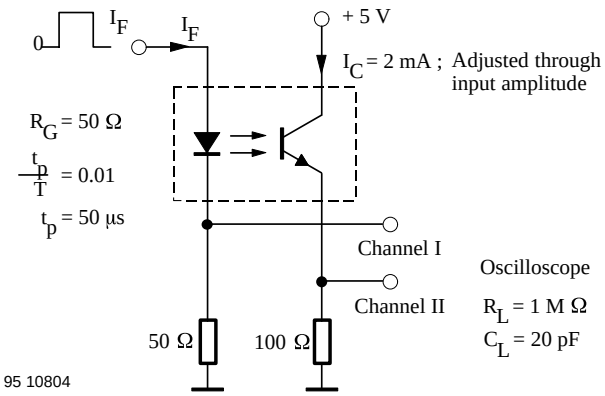
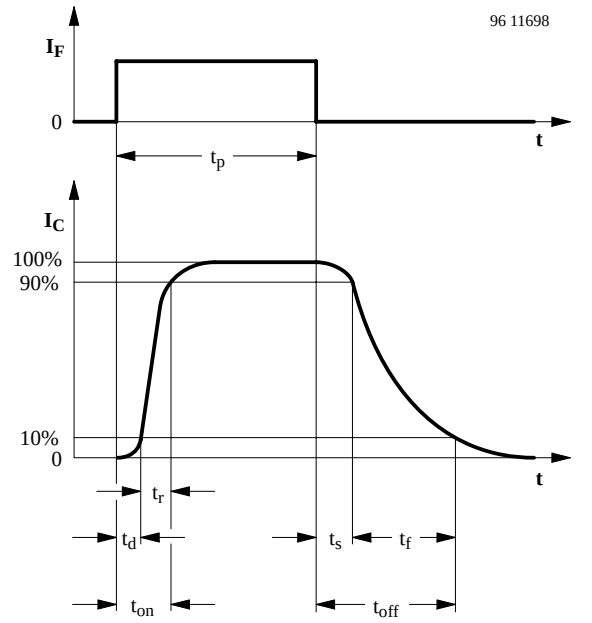


Figure 1. Test circuit, non-saturated operation



t_p	pulse duration	t_s	storage time
		t_f	fall time
t_d	delay time	t_{off} (= t_s + t_f)	turn-off time
t_r	rise time		
t_{on} (= t_d + t_r)	turn-on time		

Figure 2. Switching times

Typical Characteristics (T_{amb} = 25°C, unless otherwise specified)

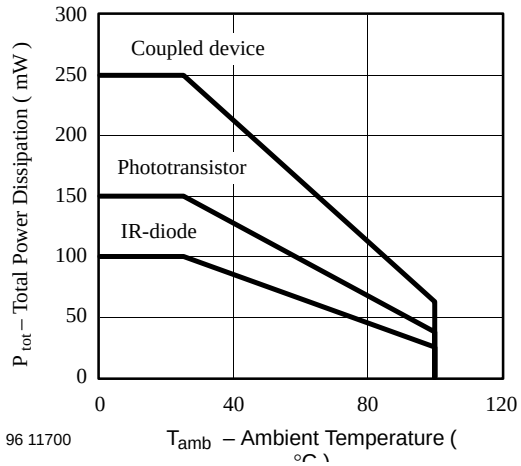


Figure 3. Total Power Dissipation vs. Ambient Temperature

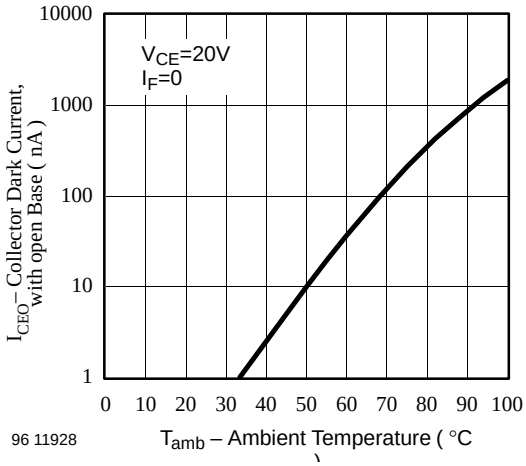


Figure 6. Collector Dark Current vs. Ambient Temperature

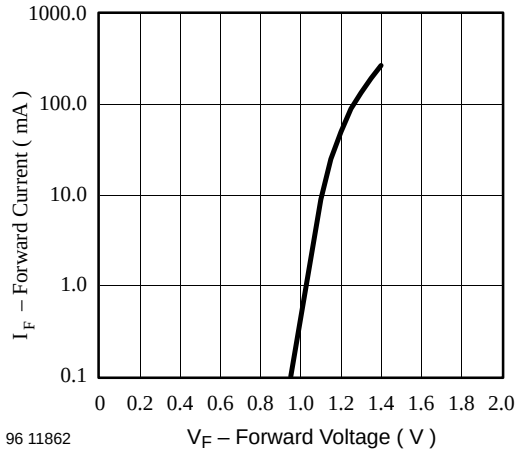


Figure 4. Forward Current vs. Forward Voltage

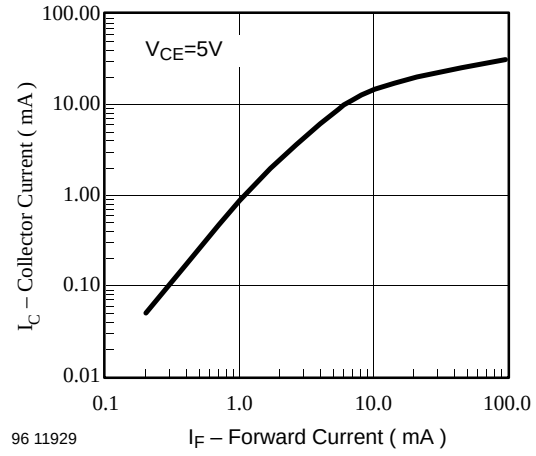


Figure 7. Collector Current vs. Forward Current

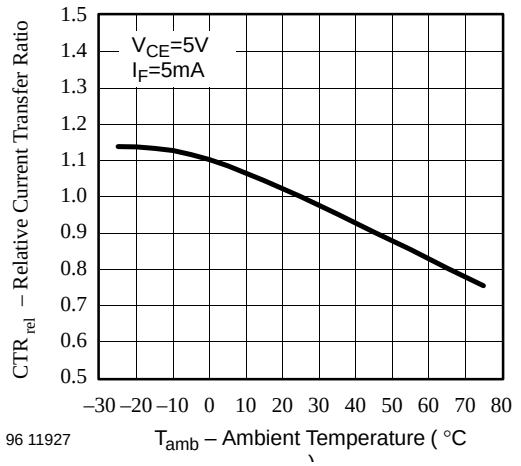


Figure 5. Relative Current Transfer Ratio vs. Ambient Temperature

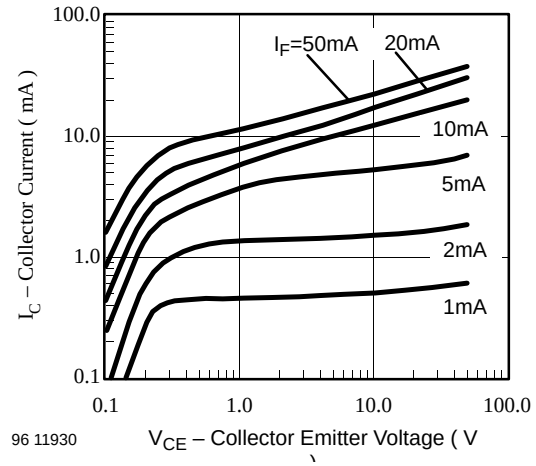


Figure 8. Collector Current vs. Collector Emitter Voltage

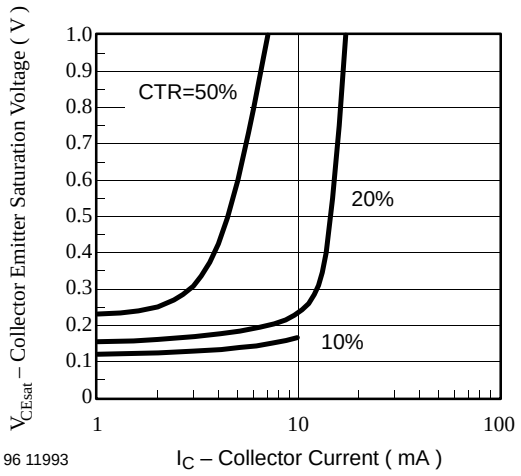


Figure 9. Collector Emitter Saturation Voltage vs. Collector Current

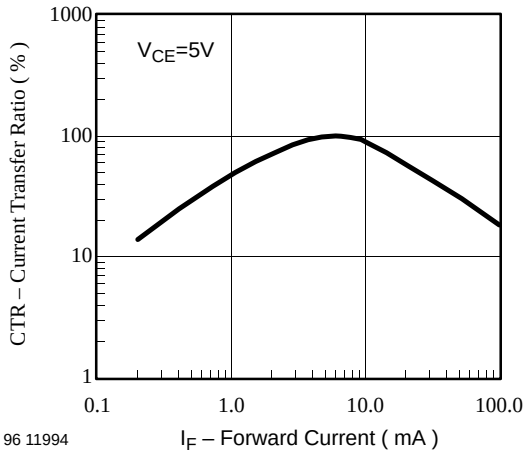


Figure 10. Current Transfer Ratio vs. Forward Current

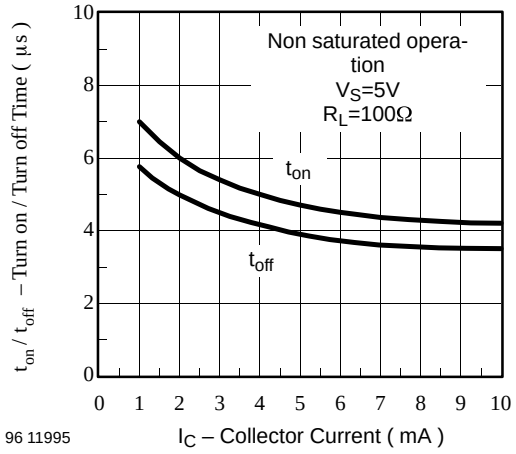


Figure 11. Turn on / off Time vs. Collector Current

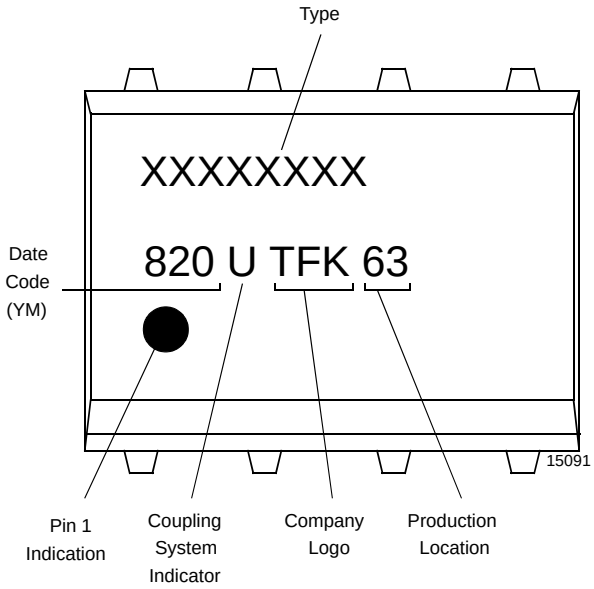
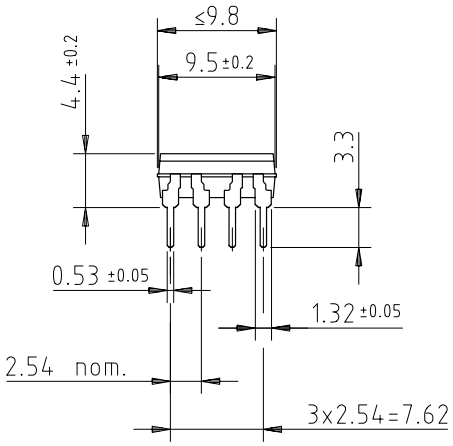
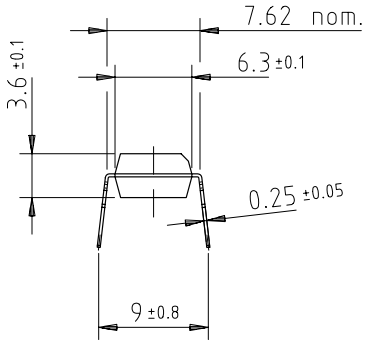


Figure 12. Marking example

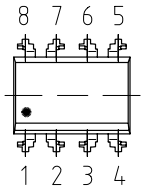
Dimensions in mm





weight: ca. 0.55 g
creepage distance: ≧ 6 mm
air path: ≧ 6 mm

after mounting on PC board



technical drawings according to DIN specifications

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